Diode Semiconductor Device - Page 1 of 1



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Inclosure M	aterial:	
Glass		
Overall Len	gth:	
0.055 inches		
Overall Dia	neter:	
0.121 inches		
Mounting M	ethod:	
Terminal		
Features Pr	ovided:	
Hermetically	sealed case	
Semicondu	ctor Material:	
Silicon		
Voltage Rat	ing In Volts Per Characteristic:	
7.0 reverse	voltage, instantaneous	
Current Rat	ing Per Characteristic:	
10.00 microa	amperes forward current, average peak	
Maximum C	perating Tempurature Per Measurement Point:	
80.0 degree	s celsius ambient air	
Precious Ma	aterial And Location:	
Terminal sur	face gold	
Terminal Ty	pe And Quantity:	
2 uninsulate	d wire lead	
Shelf Life:		
N/a		
Unit Of Mea	sure:	
Demilitariza	tion:	
No		
Fiig:		
A110a0		